









|   |  |
|---|--|
|  | <p><b>Hersteller-Teilenummer:</b> <a href="#">NTB60N06LG</a></p>   |
|   | <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p>   |
|  | <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 60A D2PAK</p>   |
|   | <p><b>Datenblätter:</b>  <a href="#">NTB60N06LG.pdf</a></p> |
|   | <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p>   |
|   | <p><b>Lagerzustand:</b> New original, 33403 pcs Stock Available.</p>   |
|   | <p><b>Liefern von:</b> Hong Kong</p>   |
| <p>Image may be representation.<br/>See specs for product details.</p>            | <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>  |

### Spezifikationen

|   |   |
|---|---|
| Teilenummer                                     | <a href="#">NTB60N06LG</a>  |
| Hersteller                                      | <a href="#">AMI Semiconductor / ON Semiconductor</a>                |
| Beschreibung                                    | MOSFET N-CH 60V 60A D2PAK   |
| Kategorie                                       | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                      | 33403 pcs Stock   |
| Serie   | -   |
| Technologie                                     | MOSFET (Metal Oxide)  |
| Betriebstemperatur                              | -55°C ~ 175°C (Tj)  |
| Befestigungsart                                 | Surface Mount   |
| Verpackung / Gehäuse                            | TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB              |
| Supplier Device-Gehäuse                         | D2PAK   |
| Verlustleistung (max)                           | 2.4W (Ta), 150W (Tj)  |
| Typ FET   | N-Channel   |
| FET-Merkmal                                     | -   |
| Drain-Source-Spannung (Vdss)                    | 60V   |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 60A (Ta)  |
| Rds On (Max) @ Id, Vgs                          | 16 mOhm @ 30A, 5V   |
| VGS (th) (Max) @ Id                             | 2V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                    | 65nC @ 5V   |
| Eingabekapazität (Ciss) (Max) @ Vds             | 3075pF @ 25V  |
| Verpackung                                      | Tube  |



















































NTB60N06LG ist neu im Original, Suche NTB60N06LG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTB60N06LG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTB60N06LG: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |   |  |   |
|--|---|--|---|
|  <p><b>NTB60N06L</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 60V 60A D2PAK</p>   |  <p><b>NTB60N06</b><br/>ON<br/>NTB60N06 ON</p>   |  <p><b>NTB5605T4G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET P-CH 60V 18.5A D2PAK</p> |  <p><b>NTB60N06LT4</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 60V 60A D2PAK</p>  |
|  <p><b>NTB6410ANG</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 100V 76A D2PAK</p> |  <p><b>NTB5860NT4G</b><br/>AMI Semiconductor / ON Semiconductor<br/>NTB5860NT4G ON</p> |  <p><b>NTB6410AN</b><br/>ON<br/>NTB6410AN ON</p>   |  <p><b>NTB60N06LT4G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 60V 60A D2PAK</p> |

### heiße Teile

Mehr

|  |  |   |  |  |
|--|--|---|--|--|
|  NTB45N06T4   |  NTB45N06T4G    |  NTB52N10    |  NTB52N10G     |  NTB52N10T4G  |
|  NTB5404N     |  NTB5404NT4G    |  NTB5405N    |  NTB5405NG     |  NTB5405NT4G  |
|  NTB5411N     |  NTB5411NG      |  NTB5411NT4G |  NTB5411NUTUMC |  NTB5412NT4G  |
|  NTB5426N     |  NTB5426NT4G    |  NTB5605P    |  NTB5605PG     |  NTB5605PT4   |
|  NTB5605PT4G  |  NTB5605T4G     |  NTB60N06    |  NTB60N06G     |  NTB60N06L    |
|  NTB60N06LT4  |  NTB60N06LT4G   |  NTB60N06T4G |  NTB6410AN     |  NTB6410ANG   |
|  NTB6410ANT4G |  NTB6411AN      |  NTB6411ANG  |  NTB6411ANT4G  |  NTB6412AN    |
|  NTB6412ANG   |  NTB6412ANT4G   |  NTB6413AN   |  NTB6413ANG    |  NTB6413ANT4G |
|  NTB6448ANG   |  NTB6448ANT4G   |  NTB65N02RG  |  NTB65N02RT4   |  NTB65N02RT4G |
|  NTB75N03     |  NTB75N03-06T4G |  NTB75N03-6G |  NTB75N03-6T4G |  NTB75N03L09G |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited